

SEMICONDUCTOR TECHNICAL DATA

KTC4379

EPITAXIAL PLANAR NPN TRANSISTOR

POWER AMPLIFIER APPLICATIONS. POWER SWITCHING APPLICATIONS.

FEATURES

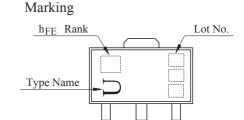
- · Low Saturation Voltage
 - : $V_{CE(sat)} = 0.5V(Max.) (I_C = 1A)$
- · High Speed Switching Time : t_{stg} =1.0 μ S(Typ.)
- · $P_C=1 \sim 2W$ (Mounted on Ceramic Substrate)
- · Small Flat Package.
- · Complementary to KTA1666.
- · Suffix $\underline{\mathbf{U}}$: Qualified to AEC-Q101.
 - ex) KTC4379-Y-RTF/H<u>U</u>

MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Collector-Base Voltage	V _{CBO}	50	V	
Collector-Emitter Voltage	V _{CEO}	50	V	
Emitter-Base Voltage	V _{EBO}	5	V	
Collector Current	I_{C}	2	A	
Base Current	I_{B}	0.4	A	
Collector Power Dissipation	$P_{\rm C}$	500	mW	
Conector Fower Dissipation	P _C *	1	W	
Junction Temperature	T _j	150	$^{\circ}$	
Storage Temperature Range	T _{stg}	-55~150	$^{\circ}$	

P_C*: KTC4379 mounted on ceramic substrate (250mm²x0.8t)

DIM MILLIMETERS 4.70 MAX 1.70 MAX 0.45+0.15/-0.10 4.25 MAX 1.50±0.10 0.40 TYP Н 1.75 MAX 0.5+0.10/-0.05 1.40 ± 0.10 0.19 ± 0.10 1. BASE 2. COLLECTOR (HEAT SINK) 3. EMITTER SOT-89



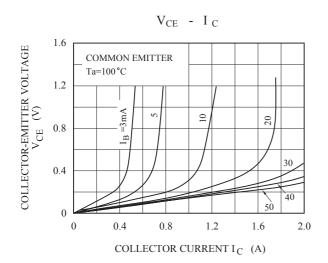
ELECTRICAL CHARACTERISTICS (Ta=25°C)

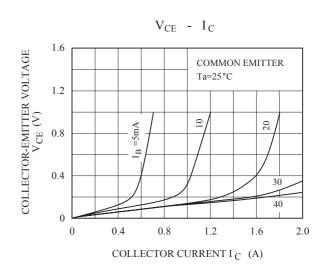
CHARA	CTERISTIC	SYMBOL	TEST CONDITION		TYP.	MAX.	UNIT
Collector Cut-off Current I_{CBO} V_{CB} =50V, I_{E} =0		-	-	0.1	μA		
Emitter Cut-off Current		I_{EBO}	$V_{EB}=5V$, $I_{C}=0$	-	-	0.1	μ A
Collector-Emitter Breakdown Voltage		V _{(BR)CEO}	$I_{C}=10\text{mA},\ I_{B}=0$	50	-	-	V
DC Current Gain		h _{FE} (1) (Note2)	V _{CE} =2V, I _C =0.5A (Note 1)	70	-	240	
		h _{FE} (2)	V _{CE} =2V, I _C =1.5A (Note 1)	40	-	-	
Collector-Emitter Saturation Voltage		V _{CE(sat)}	I _C =1A, I _B =0.05A (Note 1)	-	-	0.5	V
Base-Emitter Saturation Voltage		V _{BE(sat)}	I _C =1A, I _B =0.05A (Note 1)	-	-	1.2	V
Transition Frequency		f_T	$V_{CE}=2V, I_{C}=0.5A$	-	120	-	MHz
Collector Output Capacitance		C _{ob}	$V_{CB}=10V, I_{E}=0, f=1MHz$	-	30	-	pF
Switching Time	Turn-on Time	t _{on}	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	-	0.1	-	
	Storage Time	t _{stg}		-	1.0	-	μS
	Fall Time	t_{f}		-	0.1	-	

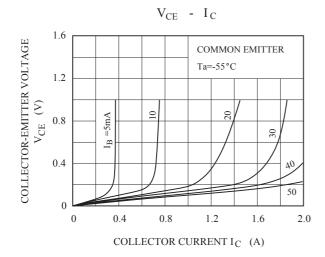
Note 1 : Pulse width $\leq 300 \,\mu\text{S}$, Duty Cycle $\leq 1\%$

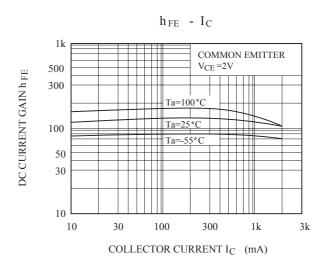
Note 2: $h_{FE}(1)$ Classification 0:70 ~ 140, Y:120 ~ 240

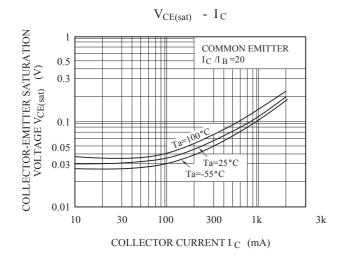
KEC

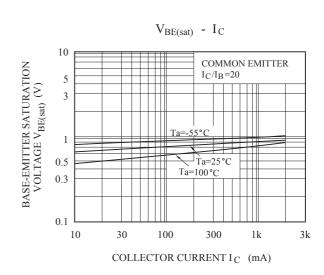


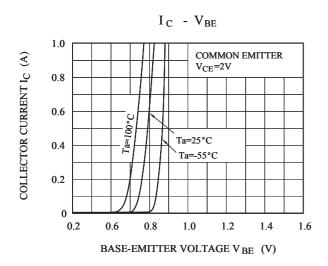


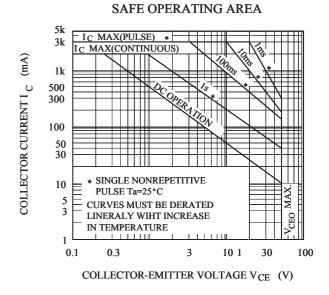




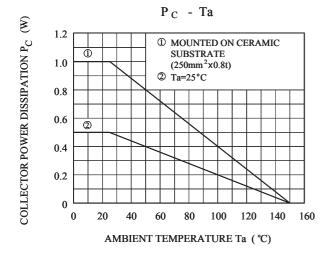








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KTC4379

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